

### 5 A Schottky Barrier Rectifier

### DESCRIPTION

This UPS540e3 in the Powermite3<sup>®</sup> package is a high efficiency Schottky rectifier that is also RoHS compliant offering high current/power capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies. In addition to its size advantages, the Powermite3<sup>®</sup> package includes a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly and a unique locking tab act as an efficient heat path to the heat-sink mounting. Its innovative design makes this device ideal for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

| ABSOLUTE MAXIMUM RATINGS AT 25° C<br>(UNLESS OTHERWISE SPECIFIED)   |  |             |      |  |
|---|--|-------------|------|--|
| Rating  | Symbol   | Value       | Unit |  |
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage  | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 40          | V    |  |
| RMS Reverse Voltage   | V <sub>R (RMS)</sub>                                   | 28          | V    |  |
| Average Rectified Output Current  | Ιo   | 5           | A    |  |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single half sine wave Superimposed<br>on Rated Load@ T <sub>c</sub> =90 °C | I <sub>FSM</sub>                                       | 100         | А    |  |
| Storage Temperature   | T <sub>STG</sub>                                       | -55 to +150 | °C   |  |

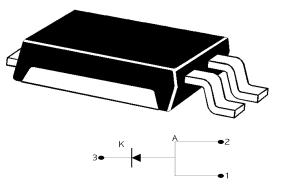
#### THERMAL CHARACTERISTICS

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| Thermal Resistance  | _                |     |          |
|---|------------------|-----|----------|
| Junction-to-case (bottom)   | R <sub>eJC</sub> | 3.2 | °C/ Watt |
| Junction to ambient (1)   | R <sub>0JA</sub> | 65  | °C/ Watt |
| (1) When mounted on FR-4 PC board using 2 oz copper with recommended minimum foot print |                  |     |          |

#### Powermite 3<sup>™</sup>

Junction Temperature



### **KEY FEATURES**

- Very low thermal resistance package
- RoHS Compliant with e3 suffix part number
- Guard-ring-die construction for transient protection
- Efficient heat path with Integral locking bottom metal tab
- Low forward voltage
- Full metallic bottom eliminates flux
  entrapment
- Compatible with automatic insertion
- Low profile-maximum height of 1mm

#### **APPLICATIONS/BENEFITS**

- Switching and Regulating Power Supplies.
- Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery
- Elimination of reverse-recovery oscillations to reduce need for EMI filtering
- Charge Pump Circuits
- Reduces reverse recovery loss with low I<sub>RM</sub>
- Small foot print 190 X 270 mils (1:1 Actual size) See mounting pad details on pg 3

#### MECHANICAL & PACKAGING

- CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750 method 2026 (consult factory for Tin-Lead plating)
- POLARITY: See figure (left)
- MARKING: S540
- WEIGHT: 0.072 gram (approx.)
- Package dimension on last page
- Tape & Reel option: 16 mm tape per Standard EIA-481-B, 5000 on 13" reel

-55 to +125

°С

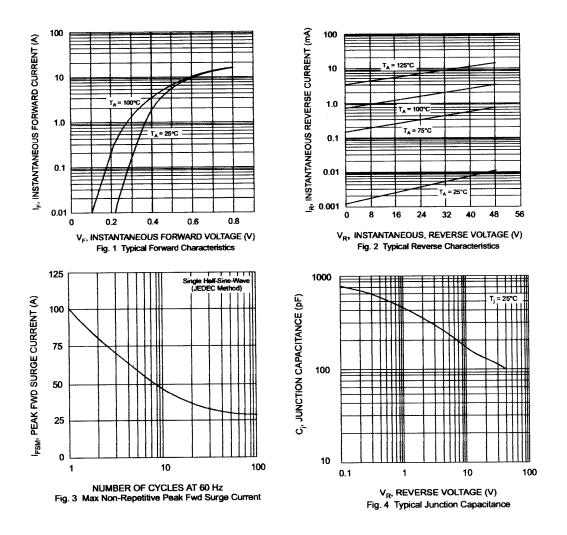
UPS340e3



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| Parameter                             | Symbol          | Conditions   | Min | Тур.                         | Max       | Units |
|---------------------------------------|-----------------|--|-----|------------------------------|-----------|-------|
| Forward Voltage (Note 1)              | V <sub>F</sub>  | $ \begin{split} I_F &= 5 \; A \;, \; T_j = 25 \; ^{o}C \\ I_F &= 5 \; A \;, \; T_j = 125 \; ^{o}C \\ I_F &= 10 \; A \;, \; T_j = 25 \; ^{o}C \\ I_F &= 10 \; A \;, \; T_j = 125 \; ^{o}C \end{split} $ |     | 0.47<br>0.45<br>0.62<br>0.59 | 0.54      | V     |
| Reverse Break Down Voltage<br>Note 1) | V <sub>BR</sub> | I <sub>R</sub> = 0.5 mA  | 40  |                              |           | V     |
| Reverse Current (Note1)               | IF              | V <sub>R</sub> = 40 V, T <sub>j</sub> = 25°C<br>V <sub>R</sub> = 40 V, T <sub>j</sub> =125 °C  |     | 0.030<br>2.5                 | 0.5<br>20 | mA    |
| Capacitance                           | CT              | V <sub>R</sub> = 4 V; F = 1 MH <sub>Z</sub>  |     | 250                          |           | pF    |

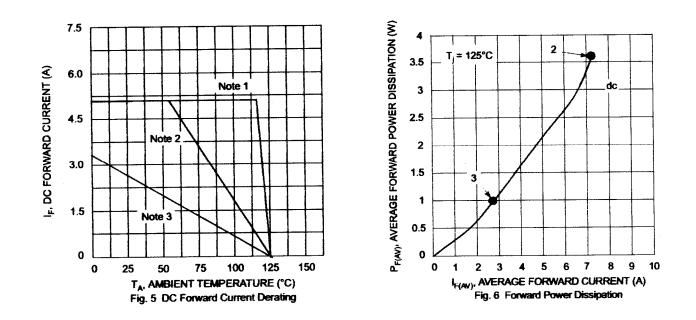
Note: 1 Short duration test pulse used to minimize self - heating effect



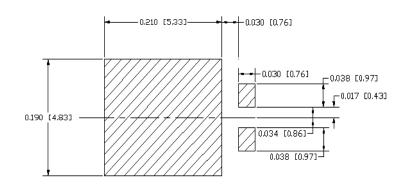
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- Notes: 1. T<sub>A</sub> = T<sub>SOLDERING POINT</sub>, R<sub>ΘJS</sub>=3.2°C/W, R<sub>Θsa</sub> = 0° C/W.
  2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". R<sub>ΘJA</sub> in range of 15-30° C/W.
  - 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout  $R_{\Theta JA}$  in range of 65° C/W. See mounting pad below.

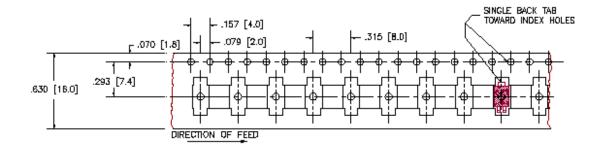


Mounting Pad Dimensions: inches [mm]

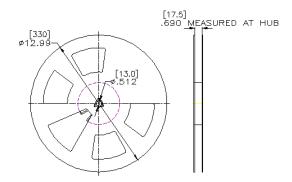


## 5 A Schottky Barrier Rectifier

16 mm TAPE



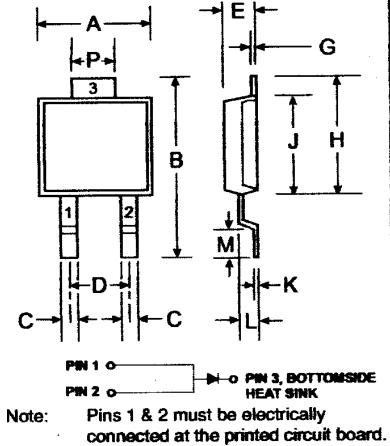
## 13 INCH REEL





## 5 A Schottky Barrier Rectifier

#### DIMENSIONS

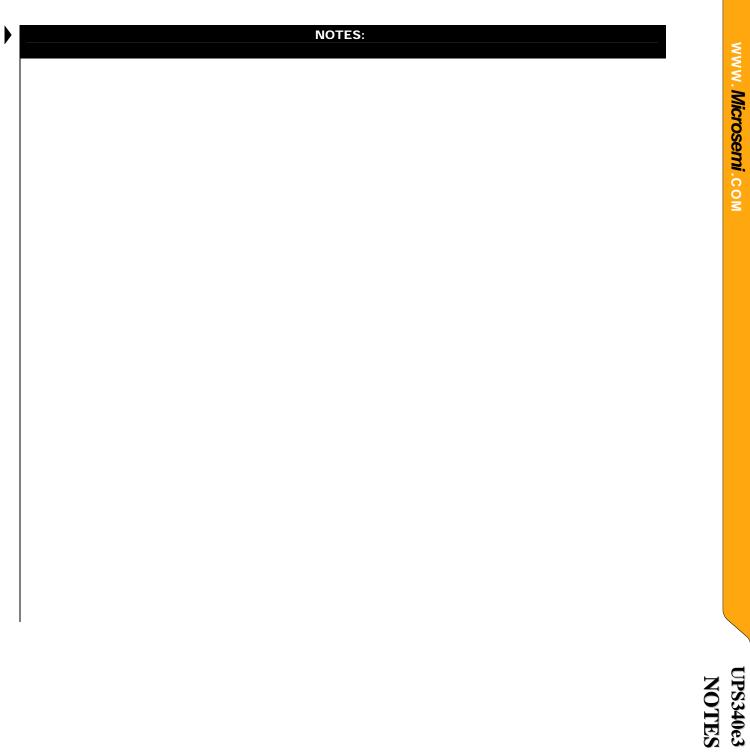


| POWERMITE®3          |          |      |
|----------------------|----------|------|
| Dim                  | Min      | Max  |
| A                    | 4.03     | 4.09 |
| В                    | 6.40     | 6.61 |
| C                    | .889 NOM |      |
| D                    | 1.83 NOM |      |
| E                    | 1.10     | 1.14 |
| G                    | .178 NOM |      |
| н                    | 5.01     | 5.17 |
| J                    | 4.37     | 4.43 |
| К                    | .178 NOM |      |
| L                    | .71      | .77  |
| M                    | .36      | .46  |
| Р                    | 1.73     | 1.83 |
| All Dimensions in mm |          |      |

UPS340e3



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